

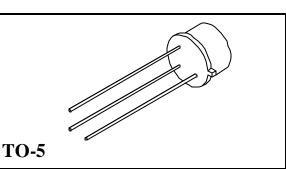
SSR1008/5 SSR1009/5 SSR1010/5

Designer's Data Sheet

FEATURES:

- Extremely Low Forward Voltage Drop
- Low Reverse Leakage
- Hermetically Sealed Package
- Guard Ring for Overvoltage Protection
- Eutectic Die Attach
- 175°C Operating Junction Temperature
- TX, TXV, or Space Level Screening Available

10 AMP 80 - 100 VOLTS SCHOTTKY RECTIFIER



MAXIMUM RATINGS

RATING	SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage and DC Blocking Voltage SSR1008/5 SSR1009/5	V _{RRM} V _{RWM}	80 90	Volts
SSR1010/5	V _R	100	
Average Rectified Output Current ^{1/}			
(Resistive Load, 60Hz, Sine Wave, TA=25°C)	Io	10	Amps
Peak Surge Current ^{1/}			
(8.3 ms Pulse, Half Sine Wave, superimposed on I_0 , allow junction to reach equilibrium between pulses, TA=25°C)	$\mathbf{I}_{\mathrm{FSM}}$	150	Amps
Operating and Storage Temperature	T _{OP} & T _{STG}	-65 to +175	°C
Maximum Thermal Resistance ^{1/}			
Junction to Case	R _{?JC}	7.0	°C/W

Notes: 1/ For optimal performance, connect leads 1 & 2 together (Anode).

NOTE: All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.	DATA SHEET #: SH0022C	DOC



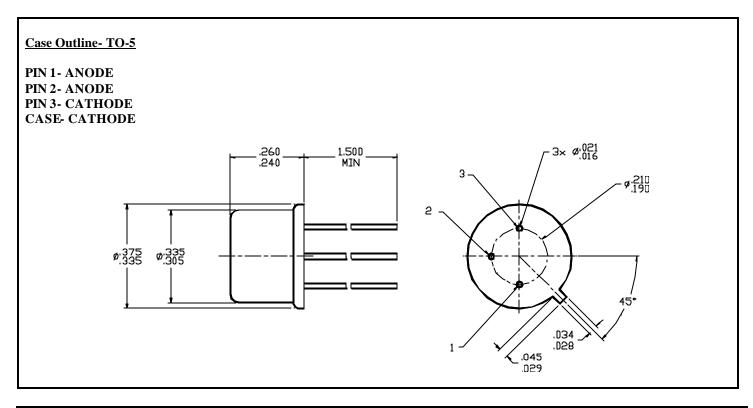
14701 Firestone Blvd * La Mirada, Ca 90638 Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com

SSR1008/5 SSR1009/5 SSR1010/5

ELECTRICAL CHARACTERISTICS			
CHARACTERISTICS	SYMBOL	MAXIMUM	UNIT
Instantaneous Forward Voltage Drop ^{2/} (I _F = 1 Adc, T _A = 25°C, 300 - 500 μ s Pulse) (I _F = 5 Adc, T _A = 25°C, 300 - 500 μ s Pulse) (I _F = 10 Adc, T _A = 25°C, 300 - 500 μ s Pulse)	$\begin{array}{c} V_{F1} \\ V_{F2} \\ V_{F3} \end{array}$	0.56 0.73 0.85	Vdc
Instantaneous Forward Voltage Drop ($I_F = 5 \text{ Adc}, T_A = -55^{\circ}\text{C}, 300 - 500 \mu\text{s}$ Pulse)	V_{F4}	0.82	Vdc
Reverse Leakage Current (Rated V_R , $T_A = 25$ °C, 300 μ s Pulse Minimum)	I _{R1}	100	μΑ
Reverse Leakage Current (Rated V_R , $T_A = 100$ °C, 300µs Pulse Minimum)	I _{R2}	5	mA
Junction Capacitance ($V_R = 10 \text{ Vdc}, T_A = 25^{\circ}\text{C}, f = 1 \text{ MHz}$)	CJ	400	pF

NOTES:

 $2/V_F$ as measured between pins 1 and 2 in common, within .100" from the case, and pin 3 directly at the case.



DATA SHEET #: SH0022C